GP1S094HCZ0F

Gap : 3mm, Slit : 0.3mm Phototransistor Output, Compact Transmissive Photointerrupter



Description

GP1S094HCZ0F is a compact-package, phototransistor output, transmissive photointerrupter, with opposing emitter and detector in a molding that provides non-contact sensing. The compact package series is a result of unique technology combing transfer and injection molding.

This device has a wide gap and positioning pins.

■Features

- 1. Transmissive with phototransistor output
- 2. Highlights:
 - Compact Size
 - · Positioning Pin to prevent misalignment
- 3. Key Parameters:
 - Gap Width : 3mm
 - Slit Width (detector side): 0.3mm
 - Package : 5.5×2.6×4.8mm
- 4. Lead free and RoHS directive compliant

■ Agency approvals/Compliance

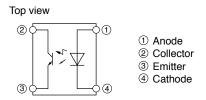
1. Compliant with RoHS directive

■ Applications

- 1. Detection of object presence or motion.
- 2. Example: printer, lens control for camera

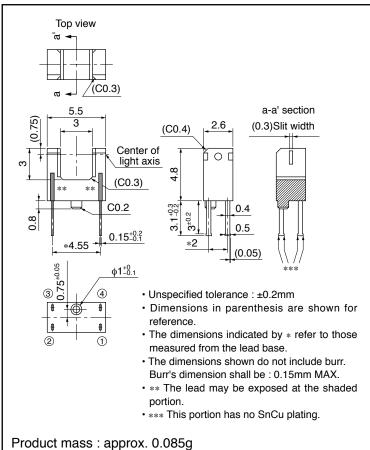
Notice The content of data sheet is subject to change without prior notice. In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARE®与控制 http://www.sensor-ic.com/ TEL:0755-83376549 FAX:0755-83376182E-MAIL: szss **公配163094HCZOF**

Internal Connection Diagram



Outline Dimensions

(Unit : mm)



Plating material : SnCu (Cu : TYP. 2%)

Country of origin Japan

SUNSTAR自动化 http://www.sensor-ic.com/ TEL: 0755₂83376489 FAX:0755-83376182 E-MAIL: szss20@163.com

空制 http://www.sensor-ic.com/ TEL:0755-83376549 FAX:0755-83376182E-MAIL: szss**级P16S094HCZOF**

■ Abs	Absolute Maximum Ratings			T _a =25°C)	
	Parameter	Symbol	Rating	Unit	
	Forward current	I _F	50	mA	
Input	Reverse voltage	V _R	6	V	
	Power dissipation	Р	75	mW	
	Collector-emitter voltage	V _{CEO}	35	V	
Output	Emitter-collector voltage	V _{ECO}	6	V	
Output	Collector current	I _C	20	mA	
	Collector power dissipation	P _C	75	mW	
Total	Total power dissipation		100	mW	
Operating temperature		T _{opr}	-25 to +85	°C	1mm or more
Storage temperature		T _{stg}	-40 to +100	°C	
*1Soldering temperature		T _{sol}	260	°C	Soldering area

*1 For 5s or less

Electro-optical Characteristics

 $(T_a=25^{\circ}C)$ Parameter Symbol Condition MIN. TYP. MAX. Unit Forward voltage $V_{\rm F}$ I_F=20mA 1.2 1.4 V _ Input Reverse current $V_R=3V$ 10 μΑ I_R _ _ Collector dark current $V_{CE}=20V$ 100 Output I_{CEO} nA _ _ $V_{CE}=5V, I_F=5mA$ 400 Collector current 40 I_{C} _ μΑ Transfer Collector-emitter saturation voltage V_{CE(sat)} $I_F=10mA$, $I_C=40\mu A$ 0.4 V _ _ charac-150 50 Rise time _ \mathbf{t}_{r} μs $V_{CE} \text{=} 5V\text{, }I_C \text{=} 100 \mu A\text{, }R_L \text{=} 1k\Omega$ teristics Response time Fall time 50 150 t_{f} μs _

Fig.1 Forward Current vs. Ambient Temperature

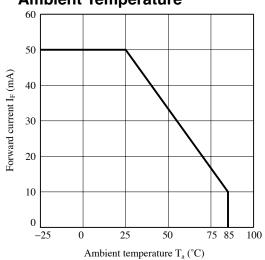
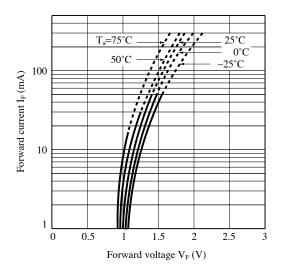


Fig.3 Forward Current vs. Forward Voltage





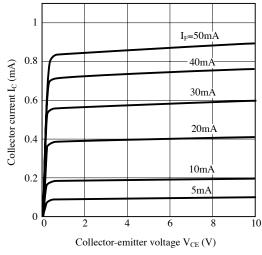


Fig.2 Power Dissipation vs. Ambient Temperature

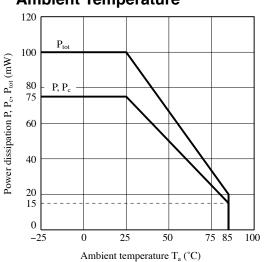
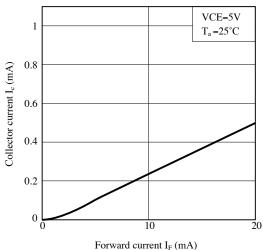


Fig.4 Collector Current vs. Forward Current





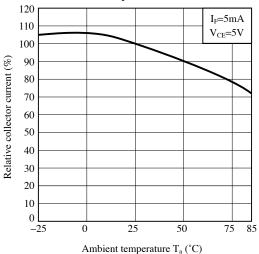


Fig.7 Collector-emitter Saturation Voltage vs. Ambient Temperature

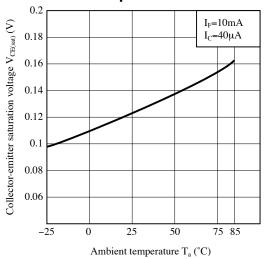
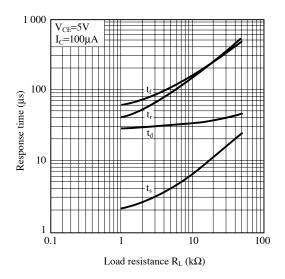


Fig.9 Response Time vs. Load Resistance





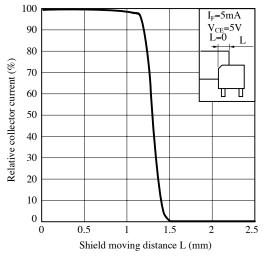


Fig.8 Collector Dark Current vs. Ambient Temperature

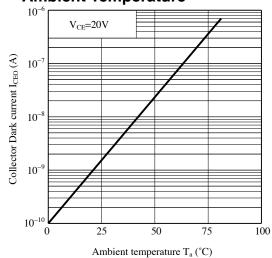
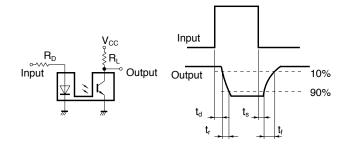
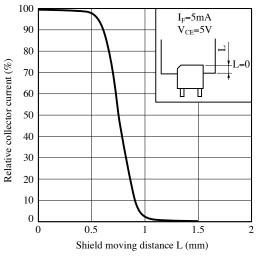


Fig.10 Test Circuit for Response Time







Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

SUNSTAR自动化 http://www.sensor-ic.com/ TEL: 0755₅83376489 FAX:0755-83376182 E-MAIL: szss20@163.com

Design Considerations

• Design guide

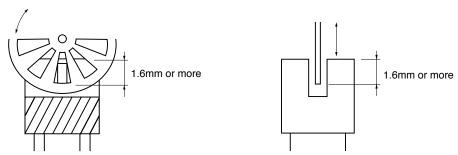
1) Prevention of detection error

To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.

2) Position of opaque board

Opaque board shall be installed at place 1.6mm or more from the top of elements.





This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photointerrupter will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Parts

This product is assembled using the below parts.

• Photodetector (qty. : 1)

Category	Material	Maximum Sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (µs)
Phototransistor	Silicon (Si)	930	700 to 1 200	20

• Photo emitter (qty. : 1)

Category	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared emitting diode (non-coherent)	Gallium arsenide (GaAs)	950	0.3

Material

Case	Lead frame	Lead frame plating
Black polyphernylene sulfide resin (UL94 V-0)	42Alloy	SnCu plating

SHAR長感与控制 http://www.sensor-ic.com/ TEL:0755-83376549 FAX:0755-83376182E-MAIL: szss**のではS094HCZOF**

Manufacturing Guidelines

Soldering Method

Flow Soldering:

Soldering should be completed below 260°C and within 5 s.

Please solder within one time.

Soldering area is 1mm or more away from the bottom of housing.

Please take care not to let any extcrhal force exert on lead pins.

Please don't do soldering with preheating, and please don't do soldering by reflow.

Hand soldering

Hand soldering should be completed within 3 s when the point of solder iron is below 350°C. Please solder within one time.

Please don't touch the terminals directly by soldering iron.

Soldered product shall treat at normal temperature.

Other notice

Please take care not to let any external force exert on lead pins.

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the cooling and soldering conditions.

• Cleaning instructions

Solvent cleaning :

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning :

Do not execute ultrasonic cleaning.

Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC). •Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

Package specification

Sleeve package

Package materials

Sleeve : Polyphernylene Stopper : Styrene-Elastomer

Package method

MAX. 100 pcs. of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

MAX. 50 sleeves in one case.

Important Notices

• The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.

• Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.

 \cdot Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:

(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- --- Space applications
- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

• If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.

• This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.

 \cdot Contact and consult with a SHARP representative if there are any questions about the contents of this publication.